Precision Quad SPDT Analog Switch

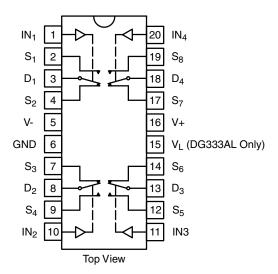
DESCRIPTION

The DG333A, DG333AL consist of four independently controlled single-pole double-throw analog switches. These monolithic switch is designed to control analog signals with a high degree of accuracy. The DG333A, DG333AL minimize measurement errors by offering low on-resistance (25 Ω typ), low leakage (20 pA typ.) and low charge injection performance. The DG333AL features micro-power operation (< 1 μW typ.). This is ideal for battery operated systems. Pin 15 is not connected on the DG333A.

An improved charge injection compensation design minimizes switching transients. These switches can handle up to \pm 22 V signals and have an improved continuous current of 30 mA.

The DG333A, DG333AL is fabricated in Vishay Siliconix's proprietary HVSG-2 CMOS process, resulting in higher speed and lower power consumption. An epitaxial layer prevents latchup. Each switch conducts equally well in both directions when on. When off, they block voltages up to the power-supply levels.

DUAL-IN-LINE, WIDE-BODY SOIC AND TSSOP



FEATURES

- ± 22 V supply voltage range
- TTL and CMOS compatible logic
- Low on-resistance (25 Ω)
- On-resistance matched between channels (< 2 Ω)
- Flat on-resistance over analog signal range ($\Delta < 3 \Omega$)
- Low charge injection (1 pC)
- Low leakage (0.2 nA)
- Fast switching (175 ns)
- Single-supply operation (5 V to 40 V)
- ESD tolerance > 2 kV per 3015.x
- Low power (< 1 μA) DG333A, DG333AL

BENEFITS

- Rail-to-rail analog signal range
- Simple logic interface
- · High precision and accuracy
- Minimal transients
- Low distortion
- Reduced power consumption
- · Improved reliability
- · Break-before-make switching action

APPLICATIONS

- Audio switching
- Test equipment
- Portable instrumentation
- · Communication systems
- PBX, PABX
- · Computer peripherals
- Mass storage systems
- Switched-capacitor networks
- Battery-powered systems



TRUTH TABLE					
LOGIC	SW1, 4, 5, 8 NORMALLY OPEN	SW2, 3, 6, 7 NORMALLY CLOSED			
0	OFF	ON			
1	ON	OFF			

Logic "0" ≤ 0.8 V Logic "1" ≥ 2.4 V

ORDERING INFORMATION						
TEMP. RANGE	PACKAGE	PART NUMBER a				
-40 °C to +85 °C	20-Pin Plastic DIP	DG333ADJ-E3				
	20-FIII Flastic DIF	DG333ALDJ-E3				
	20-Pin Wide-Body SOIC	DG333ADW-E3				
	(shipped in tubes)	DG333ALDW-E3				
	20-Pin Wide-Body SOIC	DG333ADW-T1-E3				
	(shipped in tape and reel)	DG333ALDW-T1-E3				
	20-Pin TSSOP	DG333ADQ-T1-E3				
	(shipped in tape and reel)	DG333ALDQ-T1-E3				

Note

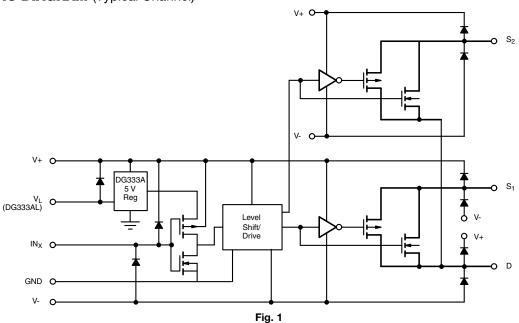
 For standard tin / lead external termination, remove the "-E3" from the ordering part number.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER		LIMIT	UNIT			
Voltages Referenced V+ to V-		44				
GND		30				
V+ to GND		40	V			
Digital Inputs ^a V _S , V _D		(V-) - 2 to (V+) + 2 or 30 mA, whichever occurs first				
Current, Any Terminal		30	- mA			
Peak Current S or D (Pulsed at 1 ms, 10) % Duty Cycle max.)	100				
Storage Temperature		-65 to +125	°C			
Power Dissipation (Package) ^b	20-Pin Plastic DIP c	890	mW			
	20-Pin Wide SOIC ^d	800				

Notes

- a. Signals on S_X , D_X , or IN_X exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 12 mW/°C above 75 °C.
- d. Derate 10 mW/°C above 75 °C.

SCHEMATIC DIAGRAM (Typical Channel)





SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP.ª	LIMITS D SUFFIX -40 °C to +85 °C			UNIT
		V+ = 15 V, V- = -15 V V _{IN} = 2.4 V or 0.8 V ^e		MIN. b	TYP. °	MAX. b	Oilii
Analog Switch				l .	_	l	L
Analog Signal Range ^d	V _{ANALOG}		Full	V-	-	V+	V
Channel On-Resistance		L = 10 m/s V = +10 V	Room	-	25	45	
Channel On-Resistance	D	$I_S = -10 \text{ mA}, V_D = \pm 10 \text{ V}$	Full	-	-	90	
On Desistance Flatness	R _{DS(on)}	$I_S = -10 \text{ mA}, V_D = \pm 5 \text{ V}$	Room	-	-	3	
On-Resistance Flatness		V+ = 16.5 V, V- = -16.5 V	Full	-	-	5	Ω
B. Malak Balana Okasa da f	. D	1 40 40 // 40 //	Room	-	-	2	-
R _{DS(on)} Match Between Channels ^f	$\Delta R_{DS(on)}$	$I_{S} = -10 \text{ mA}, V_{D} = \pm 10 \text{ V}$	Full	-	-	4	
C		V _D = 15.5 V, V _S = 15.5 V	Room	-0.25	-	0.25	nA
Source Off Leakage Current	I _{S(off)}	V+ = 16.5 V, V- = -16.5 V	Hot	-20	-	20	
Observation Lord and Oscillation		$V_D = \pm 15.5 \text{ V}, V_{S(open)} = \pm 15.5 \text{ V}$	Room	-0.75	-	0.75	
Channel On Leakage Current	I _{D(on)}	V+ = 16.5 V, V- = -16.5 V	Hot	-60	-	60	
Digital Control			1	l		L	
Input Voltage High	V _{INH}		Full	2.4	-	-	.,
Input Voltage Low	V _{INL}		Full	-	-	0.8	V
Input Current	I _{INL} or I _{INH}	V _{INH} or V _{INL}	Full	-1	-	1	μA
Dynamic Characteristics			•				•
Turn-On Time	t _{ON}	Once the transfer of the state	Room	-	-	175	
Turn-Off Time	t _{OFF}	See switching time test circuit see figure 2	Room	-	-	145	ns
Break-Before-Make Time Delay	t _D	See figure 3	Room	5	-	-	
Charge Injection ^d	Q	$C_L = 10 \text{ nF}, V_{\text{gen}} = 0 \text{ V}, R_{\text{gen}} = 0 \Omega$	Room	-	-	10	рС
Off-Isolation	OIRR	$R_L = 75 \Omega$, $C_L = 5 pF$	Room	-	72	-	.in
Channel-to-Channel Crosstalk	X _{TALK}	$V_D = 2.3 V_{RMS}$, $f = 1 MHz$	Room	-	80	-	dB
Off Capacitance	C _{OFF}	(d.M.L. V	Room	-	8	-	
Channel On Capacitance	C _{ON}	$f = 1 MHz, V_S = 0 V$	Room	-	12	-	pF
Power Supplies			•				•
Positive Supply Current	I+		Room	-	-	200	
Negative Supply Current	l-	DG333A: V _{IN} = 0 V or 5 V	Room	-1	-	-	
Positive Supply Current	I+		Room	-	-	1	μA
Logic Supply Current	ΙL	DG333AL: $V_{IN} = 0 \text{ V or } 5 \text{ V}, V_{L} = 5 \text{ V}$	Room	-	-	1	
Negative Supply Current	l-		Room	-1	-	-	
Supply Voltage Range	V+/V-		Full	± 4	-	± 22	V

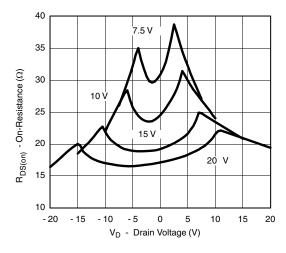
SPECIFICATIONS (Unipola	ar Supplies)						
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED $V+=12\ V,\ V-=0\ V$ $T_A=25^{\circ}C$	TEMP. a	LIMITS D SUFFIX -40 °C to +85°C			UNIT
				MIN. b	TYP. c	MAX. b	
Analog Switch							
Analog Signal Range ^d	V _{ANALOG}		Full	V-	-	V+	V
Channel On-Resistance	R _{DS(on)}	I _S = -10 mA, V _D = 10, 1 V	Room	-	35	75	Ω
Source Off Leakage Current	I _{S(off)}	V _D = 11 V, V _{S(open)} = 1 V	Room	-	-	0.25	
Channel On Leakage Current	I _{D(on)}	$V_D = 11 \text{ V}, V_{S(\text{open})} = 0 \text{ V}$ $V_D = 1 \text{ V}, V_{S(\text{open})} = \text{V}+$	Room	-	-	0.75	nA
Dynamic Characteristics					•		
Turn-On Time	t _{ON}	Con quitabing time test sixeuit and figure 2	Room	-	90	-	
Turn-Off Time	t _{OFF}	See switching time test circuit see figure 2	Room	-	45	-	ns
Break-Before-Make Time Delay	t _D	See figure 3	Room	5	10	-	
Power Supplies							•
Desitive Comple Comment	1.	DC222A.V 0.V ov.E.V	Room	-	-	200	
Positive Supply Current	I+	DG333A: V _{IN} = 0 V or 5 V	Room	-	-	1	
Positive Supply Current	I+	DC222AL.V OVer EVV EV	Room	-	-	1	μA
Logic Supply Current	ΙL	DG333AL: $V_{IN} = 0 \text{ V or } 5 \text{ V}, V_{L} = 5 \text{ V}$	Room	-	-	1	
Positive Supply Range	V+		Room	5	-	40	V

Notes

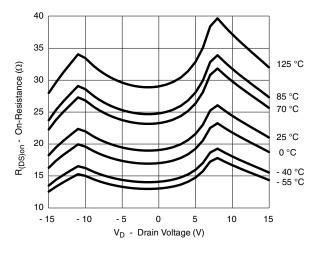
- a. Room = 25 °C, Full = as determined by the operating temperature suffix.
- b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet.
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- d. Guaranteed by design, not subject to production test.
- e. V_{IN} = input voltage to perform proper function.
- f. On-resistance match and flatness are guaranteed only for bipolar supply operation.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



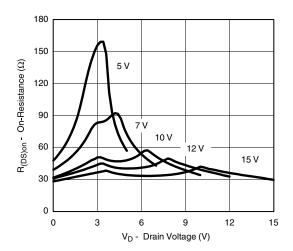
R_{DS(on)} vs. V_D (Dual Supply)



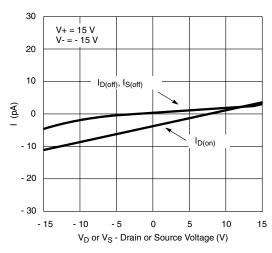
R_{DS(on)} vs. V_D and Temperature (Dual Supply)



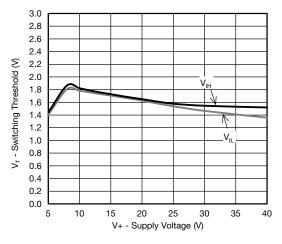
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



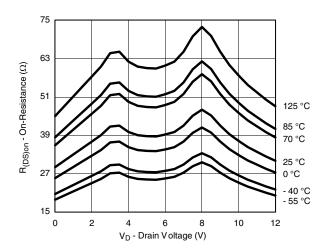
R_{DS(on)} vs. V_D (Single Supply)



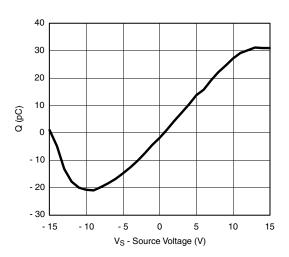
Leakage Current vs. Analog Voltage



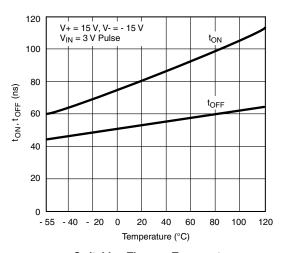
Input Switching Threshold vs. Supply Voltage



R_{DS(on)} vs. V_D and Temperature (Single Supply)



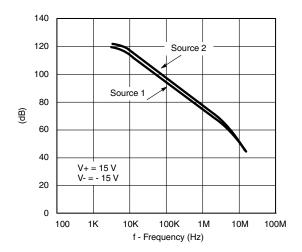
Drain Charge Injection



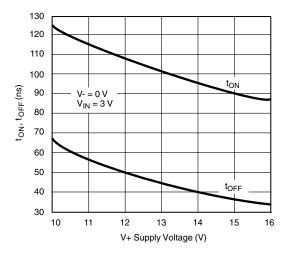
Switching Time vs. Temperature



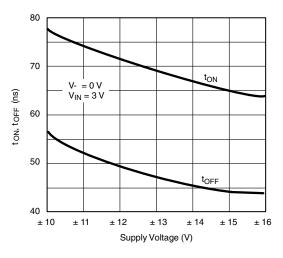
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



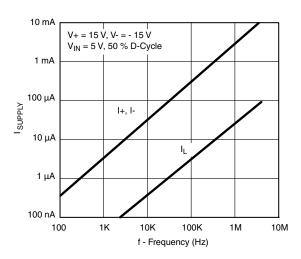
Crosstalk and Off Isolation vs. Frequency



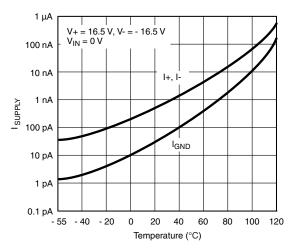
Switching Time vs. V+



Switching Time vs. Supply Voltages



Power Supply Currents vs. Switching Frequency

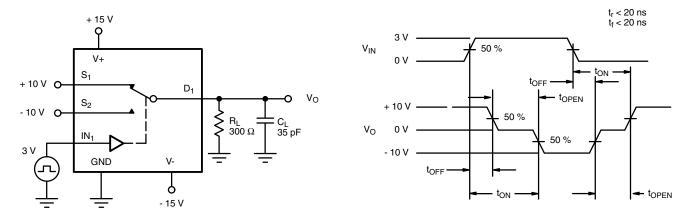


Supply Current vs. Temperature

ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



TEST CIRCUITS



Repeat Test for $\ensuremath{\text{IN}}_2$, $\ensuremath{\text{IN}}_3$ and $\ensuremath{\text{IN}}_4$

Fig. 2 - Switching Time

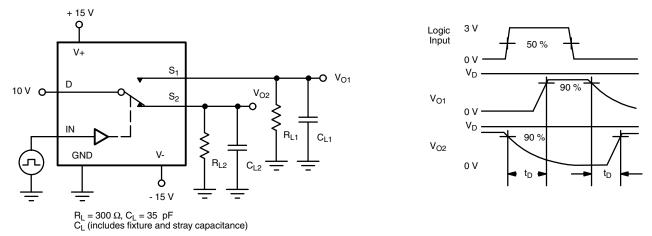


Fig. 3 - Break-Before-Make

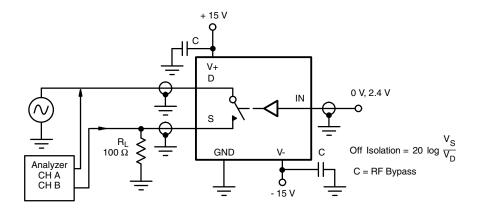


Fig. 4 - Off Isolation

TEST CIRCUITS

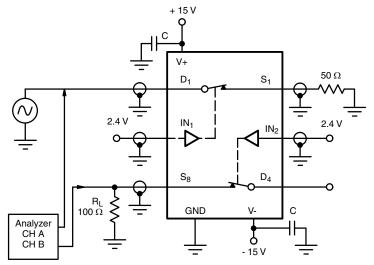


Fig. 5 - Crosstalk

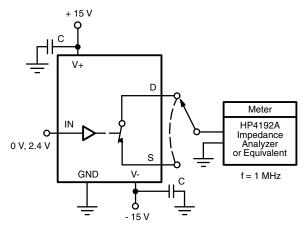


Fig. 6 - Capacitances

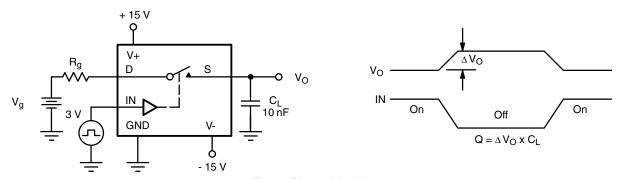


Fig. 7 - Charge Injection



APPLICATIONS

Band-Pass Switched Capacitor Filter

Single-pole double-throw switches are a common element for switched capacitor networks and filters. The fast switching times and low leakage of the DG333A, DG333AL allow for higher clock rates and consequently higher filter operating frequencies. Figure 8 shows two capacitors being switched.

The DG333A, DG333AL is capable of switching four capacitors.

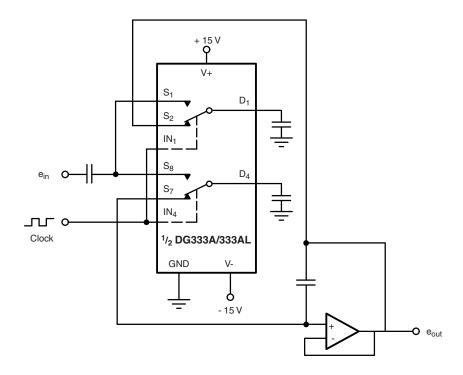
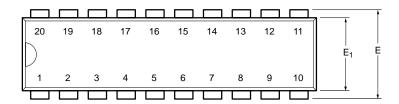


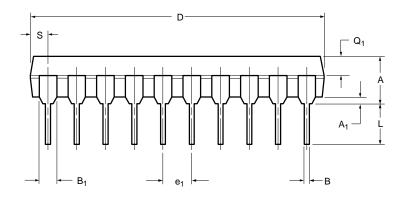
Fig. 8 - Band-Pass Switched Capacitor Filter

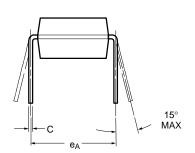
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg270803.



PDIP: 20-LEAD





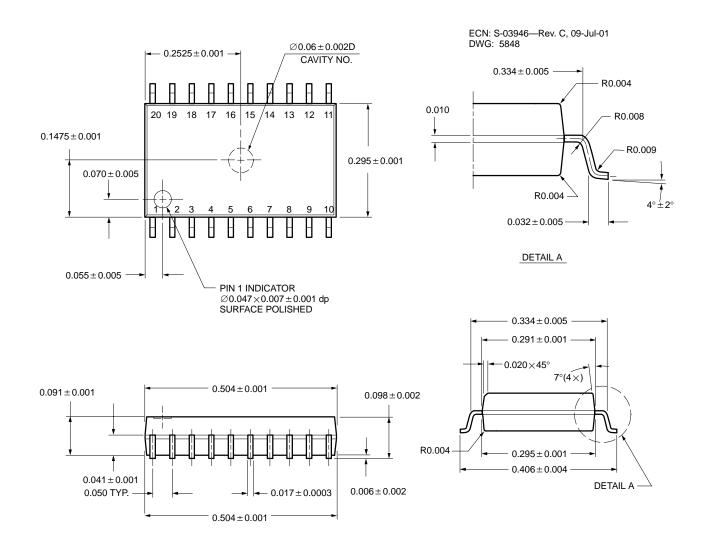


	MILLIMETERS		INC	HES	
Dim	Min	Max	Min	Max	
Α	3.81	5.08	0.150	0.200	
A ₁	0.38	1.27	0.015	0.050	
В	0.38	0.51	0.015	0.020	
B ₁	0.89	1.65	0.035	0.065	
С	0.20	0.30	0.008	0.012	
D	24.89	26.92	0.980	1.060	
Е	7.62	8.26	0.300	0.325	
E ₁	5.59	7.11	0.220	0.280	
e ₁	2.29	2.79	0.090	0.110	
e _A	7.37	7.87	0.290	0.310	
L	3.175	3.81	0.123	0.150	
Q_1	1.27	2.03	0.050	0.080	
S	1.02	2.03	0.040	0.080	
ECN: S-03946—Rev. B, 09-Jul-01 DWG: 5484					

Document Number: 71262 www.vishay.com 06-Jul-01 1



SOIC (WIDE-BODY): 20-LEAD



All Dimensions In Inches.

Document Number: 71267 www.vishay.com 06-Jul-01



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Analog Switch ICs category:

Click to view products by Vishay manufacturer:

Other Similar products are found below:

PI5A100QEX DG9233EDY-GE3 NLAS4684FCTCG NLAS5223BLMNR2G NLV74HC4066ADR2G MC74HC4067ADTG

NLX2G66DMUTCG NS5A4684SMNTAG 732480R 733995E 425541DB 425528R 099044FB FSA221UMX MAX4888ETI+T

NLAS5123MNR2G NLAS7222AMTR2G MAX14807ECB+ MAX4968ECM+ PI5A4157CEX NLV14066BDG LC78615E-01US-H

PI5A4599BCEX PI5A3157BZUEX NLAS4717EPFCT1G PI5A3167CCEX MAX4744ELB+T MAX4802ACXZ+ SLAS3158MNR2G

PI5A392AQE MAX4744HELB+T PI5A4157ZUEX MC74HC4067ADTR2G PI5A4158ZAEX PI5A3166TAEX MAX4901EBL+T

MAX14510EEVB+T PI3A3899ZTEX MAX4996ETG+T MAX4889AETO+T MAX14508EEVB+T MAX4701ETE+T MAX4996LETG+T

NLX2G66FCTAG TMUX136RSER HV2605FG-G DG302BDJ-E3 ADG741BKSZ-REEL ADG742BKSZ5-REEL7 PI5A100WE